

TRANSFORMING STORAGE WITH INNOVATIONS IN NON-VOLATILE MEMORY

Bill Bollengier, Director

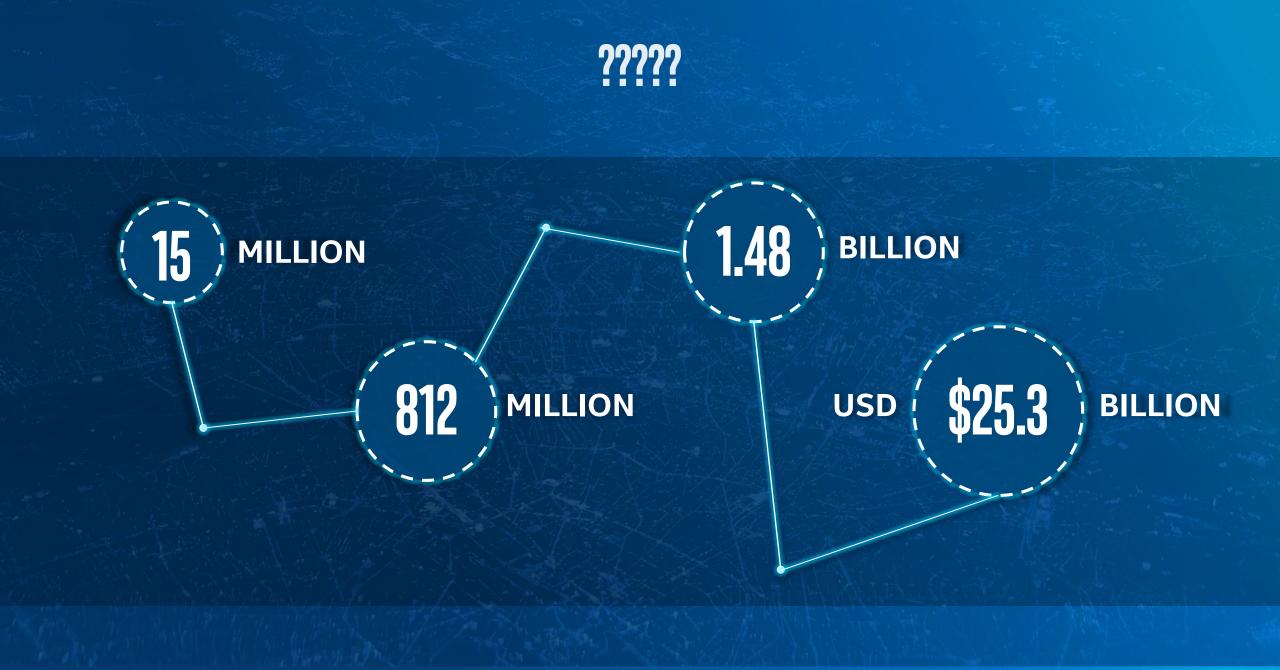
Intel Non-volatile Memory Solutions Group

WE ARE IN A DATA-CENTRIC WORLD

All data must be stored, processed, analyzed







3

ALIBABA* 'SINGLES DAY' 2017



*Other names and brands may be claimed as the property of others Source: www.forbes.com/sites/helenwang/2017/11/12/alibabas-singles-day-by-the-numbers-a-record-25-billion-haul/#52d3a77d1db1



DATA GROWTH IS HAPPENING ALL OVER

















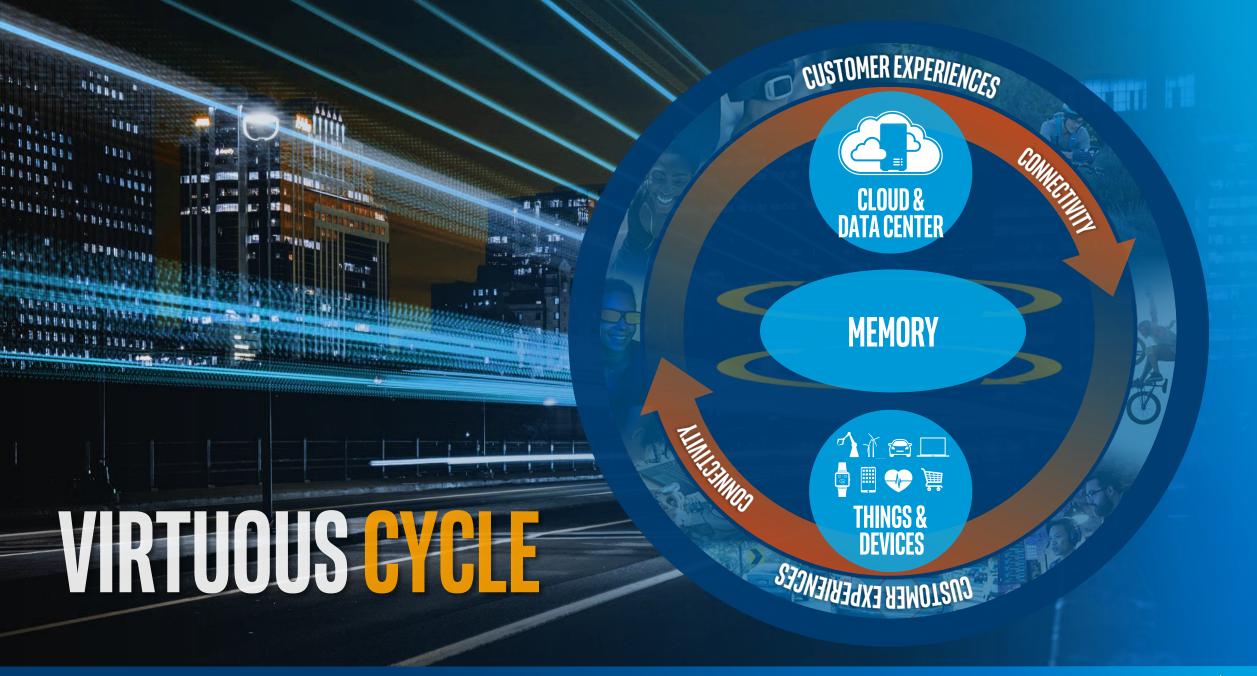




Source: http://www.cisco.com/c/en/us/solutions/service-provider/vni-network-traffic-forecast/infographic.html
Source: http://www.cisco.com/c/en/us/solutions/collateral/service-provider/global-cloud-index-gci/Cloud_Index_White_Paper.html
Source: https://dataflog.com/read/self-driving-cars-create-2-petabytes-data-annually/172

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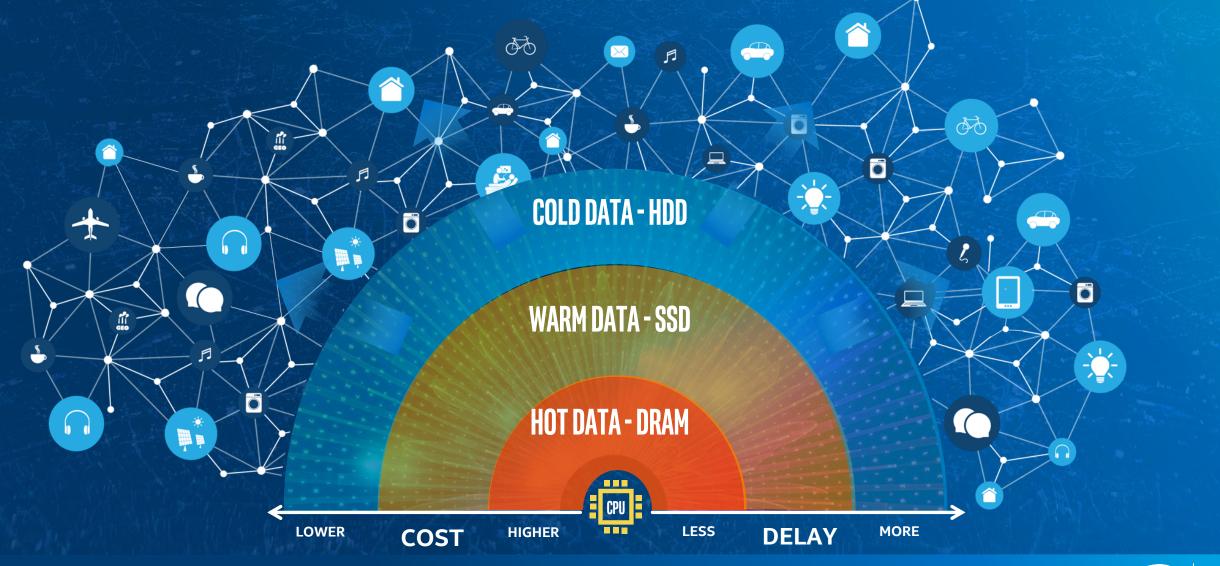




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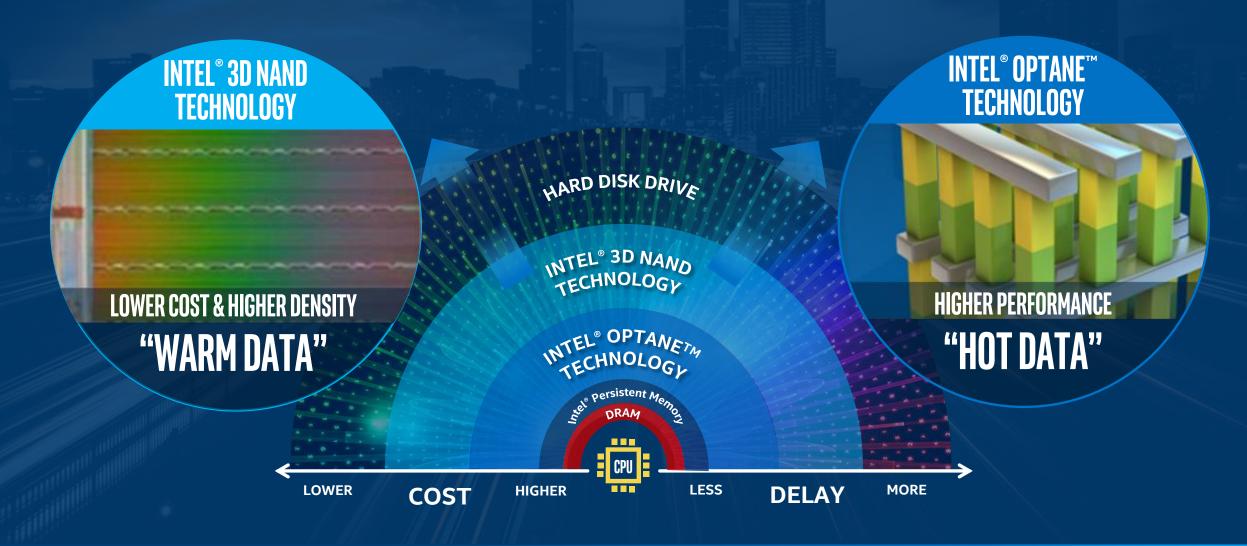


DATA IS STORED BY DIFFERENT TIERS





INTEL IS INVESTING IN 2 TECHNOLOGIES





INTEL[®] OPTANETM TECHNOLOGY

Highest Performance: Break The Bottleneck



THE VALUE IS IN THE GAP



SRAM Latency: 1X Size of Data: 1X DRAM Latency: ~10X Size of Data: ~100X







New experiences

New levels of scale

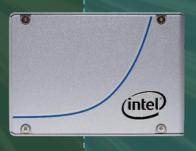
Accelerate existing apps

STORAGE

NAND SSD

Latency: ~100,000X Size of Data: ~1,000X HDD

Latency: ~10 Million X Size of Data: ~10,000X



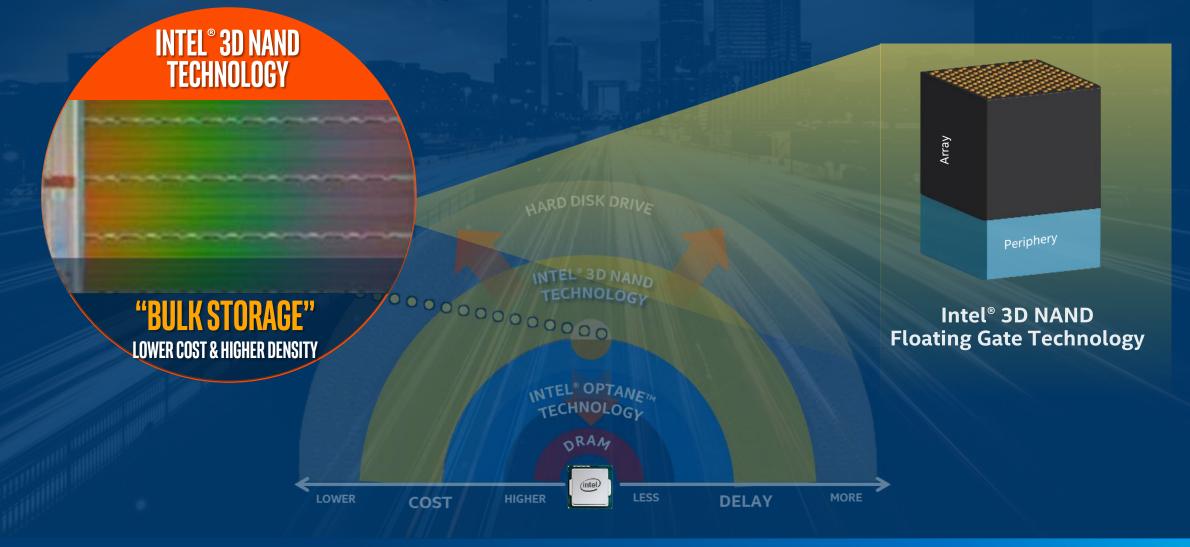
Technology claims are based on comparisons of latency, density and write cycling metrics amongst memory technologies recorded on published specifications of in-market memory products against internal Intel specifications.

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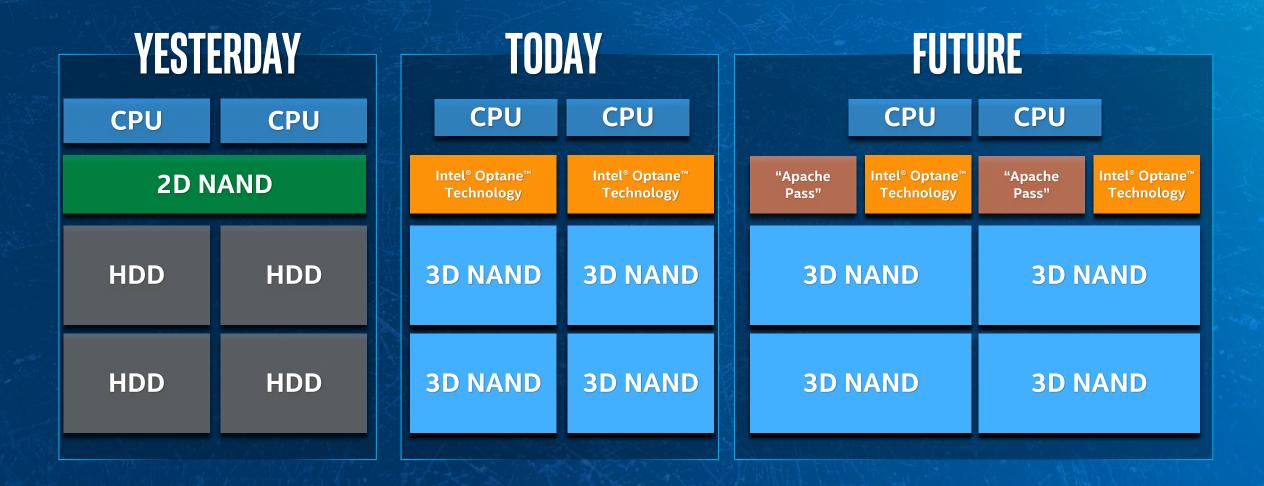
INTEL® 3D NAND TECHNOLOGY

Highest Density & Lowest Cost





A PORTFOLIO OF SOLUTION COMPONENTS

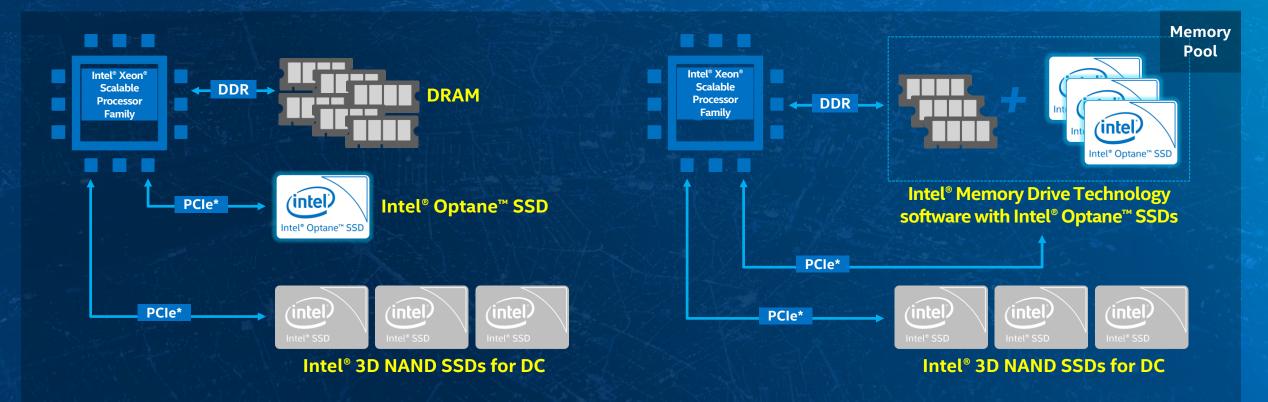




INTEL® OPTANE[™] TECHNOLOGY FOR DATA CENTER CONFIGURATIONS

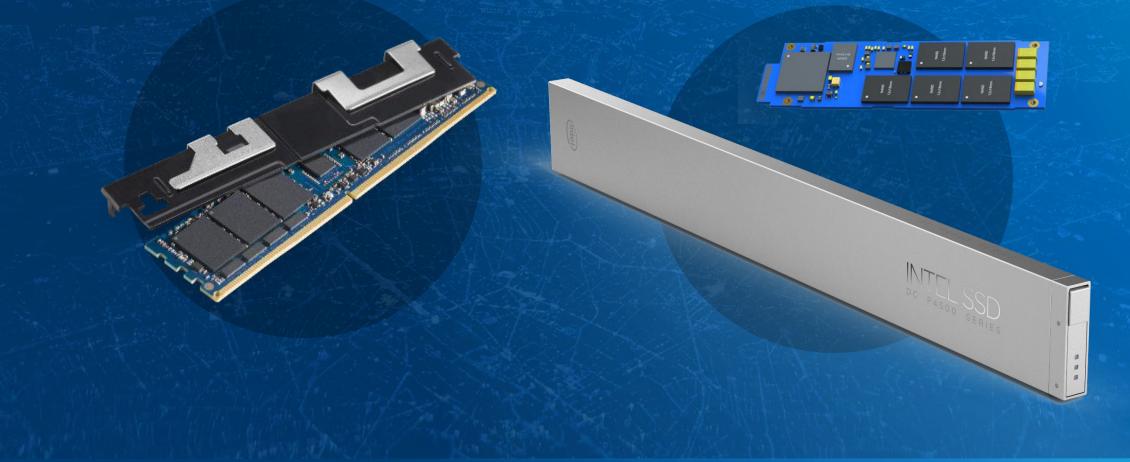
FAST STORAGE AND CACHING

EXTEND MEMORY



*Other names and brands may be claimed as the property of others.

ENABLING NEW USAGES & FORM FACTORS



THE BEST OF BOTH WORLDS

DRAM ATTRIBUTES

Performance comparable to DRAM at low latencies¹

NAND SSD ATTRIBUTES

Data persistence with higher capacity than DRAM²

3D XPoint™ Technology



INTEL® OPTANETH TECHNOLOGY + 3D NAND TECHNOLOGY

Plenty and affordable memory

High performance storage (latency, bandwidth, QoS, endurance)

Application managed memory

More and extended VMs

Capacity for In-Memory Database

Super-fast storage

Larger memory pools

PROVIDING LOWER AND CONSISTENT LATENCY WITH MORE CAPACITY PER DOLLAR



"RULER" FORM FACTOR



.

EDSFF Short



https://edsffspec.org



BUILT IN SERVICEABILITY

Programmable LEDs to quickly locate failed drives, offline drives, and unpopulated slots

Carrier-less design with integrated latch removes need for drive carriers Enclosure Management with slot level **power control** enables single drive isolation or system level power loss

NVM Solutions Group



1PB IN 1U



STORAGE CAPACITY

1PB IN 1U INTEL® 3D NAND SSD, 32TB RULER IN 2018

Opening up new use cases in warm storage with disruptive total cost of ownership

NVM Solutions Group





pmem.io

AT STATE

software.intel.com/en-us/persistent-memory

edsffspec.org





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1.Source: http://www.cisco.com/c/en/us/solutions/service-provider/vni-network-traffic-forecast/infographic.html

2.Source: http://www.cisco.com/c/en/us/solutions/collateral/service-provider/global-cloud-index-gci/Cloud_Index_White_Paper.html

3.Source: https://dataflog.com/read/self-driving-cars-create-2-petabytes-data-annually/172

4.Source – Intel. Measured data. Comparing Intel 32 tier TLC NAND die (Intel® Pro6000p/600p Series) to Samsung 32 tier TLC NAND die.

5.Test and System Configuration: Intel[®] Server Board S2600WTTR, Intel[®] Xeon[®] E5-2699 v3, Speed: 2.30GHz, Intel BIOS: Internal Release, DRAM: DDR3 – 32GB, OS: Linux* Centos* 7.0 kernel 4.8, Intel[®] SSD DC P4500 2TB. Testing performed by Intel. Comparing with Intel[®] SSD DC S3520 1.6TB, http://www.intel.com/content/www/us/en/solid-state-drives/solid-sta

6.10X Lower AFR: Source - Intel. Intel SSD Annualized Fail Rate Report for all of 2015.

For footnote 7-11 below - Common configuration. Baseline (HDD) - Intel[®] Core[™] i5-7500 Processor, 65W TDP, 4C4T, Turbo up to 3.8GHz, Memory: 2x4GB DDR4-2400, Storage: Western Digital* 1TB 7200RPM WD1003FZEX, Intel HD Graphics 630, OS: Windows* 10. Intel[®] Optane[™] Memory. Same configuration as above with 16GB Intel[®] Optane[™] Memory Module (Engineering Sample). Gaming workloads were tested with same configuration, except using a discrete graphics card (NVIDIA* (EVGA) GTX 1080) with and without 16GB Intel[®] Optane[™] Memory Module. Tested with 16GB Intel[®] Optane[™] Memory Engineering Samples. Results may vary in final product, but we have a high confidence level that there will be no significant differences in performance.

7.Everyday Tasks - SYSmark* 2014 SE - benchmark from the BAPCo* consortium that measures the performance of Windows* platforms. SYSmark* tests four usage scenarios: Office Productivity, Media Creation, Data/Financial Analysis, and Responsiveness. SYSmark* contains real applications from Independent Software Vendors such as Microsoft* and Adobe*.

8.Browser Launch Workload – Workload developed by Intel® measuring the time elapsed to launch Google* Chrome

9.Game Launch & Level Load Workload – Workload developed by Intel[®] measuring the time elapsed to launch Bethesda Softworks* Fallout 4 and reach the Main Menu with intro videos disabled (Launch), and the time elapsed from the Main Menu to completion of level loading (Level Load)

10.Email Launch Workload – Workload developed by Intel® measuring the time elapsed to launch Microsoft* Outlook 2016 and load with a 250mb local data file

11. Windows* File Search – Workload developed by Intel® measuring the time elapsed using Microsoft* Windows File Search to locate a specified file in a non-indexed directory

12.Responsiveness defined as average read latency measured at queue depth 1 during 4k random write workload. Measured using FIO 2.15. Common configuration - Intel 2U PCSD Server ("Wildcat Pass"), OS CentOS 7.2, kernel 3.10.0-327.el7.x86_64, CPU 2 x Intel® Xeon® E5-2699 v4 @ 2.20GHz (22 cores), RAM 396GB DDR @ 2133MHz. Intel drives evaluated - Intel® Optane™ SSD DC P4800X 375GB and Intel® SSD DC P3700 1600GB. Samsung drives evaluated – Samsung® SSD PM1725a, Samsung® SSD PM1725, Samsung® PM963, Samsung® PM953. Micron drive evaluated – Micron® 9100 PCIe® NVMe™ SSD. Toshiba drives evaluated – Toshiba® ZD6300. Test – QD1 Random Read 4K latency, QD1 Random RW 4K 70% Read latency, QD1 Random Write 4K latency using fio-2.15.

13.System configuration: Common – 2 x 5-node Ceph clusters both on Ceph BlueStore Kraken release 11.0.2, each node with Ubuntu 16.04 updated to Linux kernel 4.6, each cluster using 4 x Intel® SSD DC P3520 2TB as OSD (object storage device). All NAND cluster with each node – Intel® SSD DC P3700 1.6TB for metadata (db + WAL), 2 x Intel® Xeon E5, NIC 4x10GbE. Cluster using Intel® Optane SSDs: each node – Intel® Optane[™] SSD 187GB for metadata (db + WAL), 2 x Intel® Xeon® E5 Haswell, NIC 2x10GbE. Test – latency based on 16K RW from 100 clients with QD2 at >99.9% latency, performance based on 2 cluster RW (4K/8K/16K) results, NAND cluster limited by P3700, Optane scaling performance is estimation based on 4K RW data of Optane and P3520 SSD.

14.Xeon E5v4 All-DRAM memory configuration hardware limited up to 3TB (assumes 24 DIMM x 128GB). In a 2-socket CPU configuration, Intel® Memory Drive Technology software supports up to 20 x 375TB Intel® Optane[™] SSD DC P4800X for a total addressable space of 6TB, while DRAM as a cache is only 3TB. Attainable capacity depends on server configuration. Please consult your server manufacturer.

15.Xeon E5v4 All-DRAM memory configuration hardware limited up to 3TB (assumes 24 DIMM x 128GB). In a 2-socket CPU configuration, Intel® Memory Drive Technology software supports up to 20 x 1.5TB Intel® Optane™ SSD DC P4800X for a total addressable space of 24TB, while DRAM as a cache is only 3TB. Attainable capacity depends on server configuration. Please consult your server manufacturer.

